## KW HKL531.TE

### OSLON® Black Flat S

OSLON Black Flat S is able to meet a wide range of requirements. The SMT device is very stable, durable and can be used with standard processes. A new solder pad layout allows for high reliability and improved thermal management. The compact chips not only deliver high light output, they are also individually addressable with an ensured chip-to-chip contrast which makes this LED an ideal solution for Adaptive Driving Beam (ADB).





### **Applications**

- Headlamps, LED & Laser & Night Vision

#### Features:

- Package: SMD epoxy package

- Chip technology: UX:3

- Typ. Radiation: 120° (Lambertian emitter)

— Color: Cx = 0.322, Cy = 0.334 acc. to CIE 1931 (● ultra white)

- Corrosion Robustness Class: 3B

- Qualifications: AEC-Q102 Qualified

- ESD: 8 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 3B)



Ordering Information		
Туре	Luminous Flux <sup>1)</sup> $I_F = 1000 \text{ mA}$ $\Phi_V$	Ordering Code
KW HKL531.TE-F0F8-ebvFfcbB46-4LZL	1310 1760 lm	Q65112A8333



Maximum Ratings			
Parameter	Symbol		Values
Operating Temperature	$T_{op}$	min. max.	-40 °C 125 °C
Storage Temperature	T <sub>stg</sub>	min. max.	-40 °C 125 °C
Junction Temperature	$T_{j}$	max.	150 °C
Junction Temperature for short time applications*	T <sub>j</sub>	max.	175 °C
Forward Current T <sub>S</sub> = 25 °C	I <sub>F</sub>	min. max.	50 mA 1500 mA
Surge Current $t \le 10 \ \mu s; \ D = 0.005 \ ; \ T_s = 25 \ ^{\circ}C$	I <sub>FS</sub>	max.	3000 mA
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 3B)	$V_{ESD}$		8 kV
Reverse current 2)	I <sub>R</sub>	max.	200 mA

<sup>\*</sup> The median lifetime (L70/B50) for Tj = 175 $^{\circ}$ C is 100h.

### KW HKL531.TE

## **Characteristics**

 $I_F$  = 1000 mA;  $T_S$  = 25 °C

Parameter	Symbol		Values
Chromaticity Coordinate 3)	Cx Cy	typ.	0.322 0.334
Viewing angle at 50% I <sub>v</sub>	2φ	typ.	120 °
Radiating surface	$A_{color}$	typ.	4,4 mm²
Forward Voltage <sup>4)</sup> I <sub>F</sub> = 1000 mA	$V_{F}$	min. typ. max.	10.90 V 12.05 V 14.90 V
Reverse voltage (ESD device)	$V_{_{RESD}}$	min.	45 V
Reverse voltage <sup>2)</sup> I <sub>R</sub> = 20 mA	$V_R$	max.	1.2 V
Chip to Chip Contrast	-	typ.	1:200
Real thermal resistance junction/solderpoint 5)	$R_{ ext{thJS real}}$	typ. max.	1.00 K / W 1.20 K / W
Electrical thermal resistance junction/solderpoint $^{5)}$ with efficiency $\eta_e$ = 37 %	$R_{ ext{thJS elec.}}$	typ. max.	0.63 K / W 0.76 K / W



# **Brightness Groups**

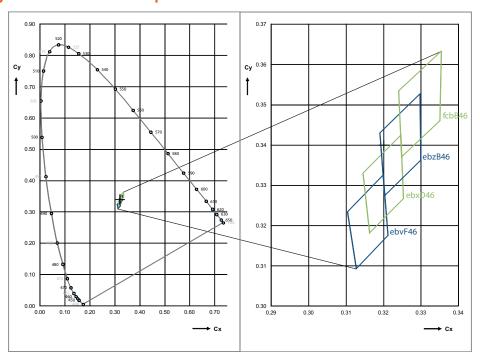
Group	Luminous Flux <sup>1)</sup> $I_F = 1000 \text{ mA}$ min. $\Phi_V$	Luminous Flux <sup>1)</sup> $I_F = 1000 \text{ mA}$ max. $\Phi_V$	Luminous Intensity $^{6)}$ $I_F = 1000 \text{ mA}$ typ. $I_V$	
F0	1310 lm	1355 lm	440 cd	
F1	1355 lm	1400 lm	450 cd	
F2	1400 lm	1450 lm	470 cd	
F3	1450 lm	1500 lm	490 cd	
F4	1500 lm	1550 lm	500 cd	
F5	1550 lm	1600 lm	520 cd	
F6	1600 lm	1650 lm	540 cd	
F7	1650 lm	1700 lm	550 cd	
F8	1700 lm	1760 lm	570 cd	

# **Forward Voltage Groups**

Group	Forward Voltage 4)	Forward Voltage 4)	
	$I_{F} = 1000 \text{ mA}$	$I_{F} = 1000 \text{ mA}$	
	min.	max.	
	$V_{F}$	$V_{F}$	
4L	10.90 V	11.90 V	
QL	11.90 V	12.90 V	
ML	12.90 V	13.90 V	
ZL	13.90 V	14.90 V	



# **Chromaticity Coordinate Groups** 3)



# **Chromaticity Coordinate Groups** 3)

Group	Сх	Су	Group	Cx	Су
ebvF46	0.3127	0.3093	ebzB46	0.3203	0.3274
	0.3212	0.3175		0.3299	0.3361
	0.3199	0.3325		0.3298	0.3526
	0.3104	0.3234		0.3190	0.3430
ebxD46	0.3163	0.3181	fcbB46	0.3248	0.3370
	0.3253	0.3266		0.3350	0.3460
	0.3246	0.3424		0.3355	0.3633
	0.3145	0.3330		0.3241	0.3534



## **Group Name on Label**

Example: F0-ebvF46-4L

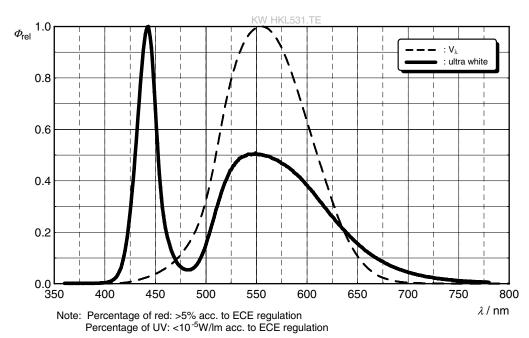
Brightness Color Chromaticity Forward Voltage

F0 ebvF46 4L



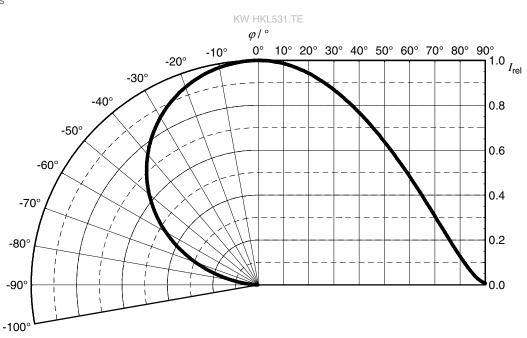
# Relative Spectral Emission 6)

$$\Phi_{rel}$$
 = f ( $\lambda$ ); I<sub>F</sub> = 1000 mA; T<sub>S</sub> = 25 °C



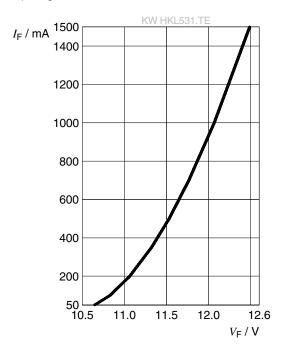
### Radiation Characteristics 6)

 $I_{rel} = f(\phi); T_S = 25 °C$ 



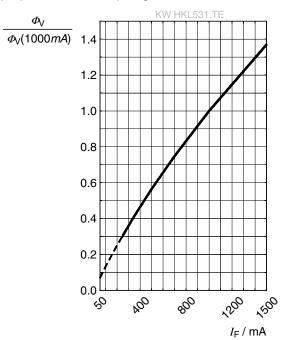
### Forward current 6), 7)

$$I_F = f(V_F); T_S = 25 \, ^{\circ}C$$



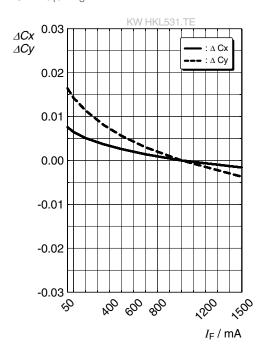
### Relative Luminous Flux 6), 7)

$$\Phi_{V}/\Phi_{V}(1000 \text{ mA}) = f(I_{F}); T_{S} = 25 \text{ °C}$$



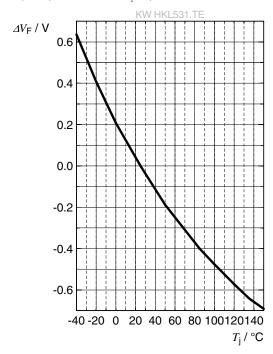
## Chromaticity Coordinate Shift 6)

$$\Delta Cx$$
,  $\Delta Cy = f(I_F)$ ;  $T_S = 25 \, ^{\circ}C$ 



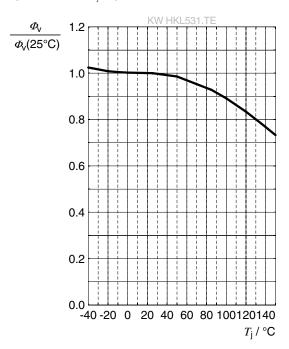
### Forward Voltage 6)

$$\Delta V_F = V_F - V_F (25 \ ^{\circ}C) = f(T_j); I_F = 1000 \ mA$$



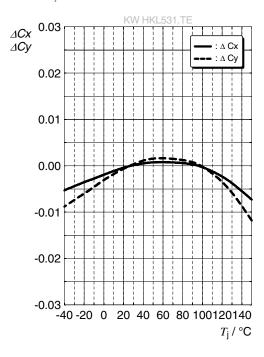
### Relative Luminous Flux 6)

$$\Phi_{v}/\Phi_{v}(25 \text{ °C}) = f(T_{i}); I_{F} = 1000 \text{ mA}$$



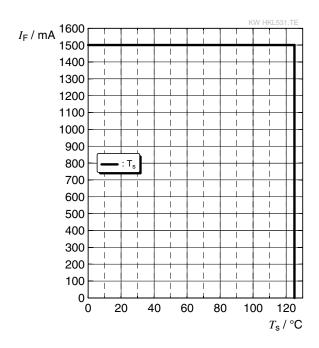
# Chromaticity Coordinate Shift 6)

 $\Delta Cx$ ,  $\Delta Cy = f(T_i)$ ;  $I_F = 1000 \text{ mA}$ 



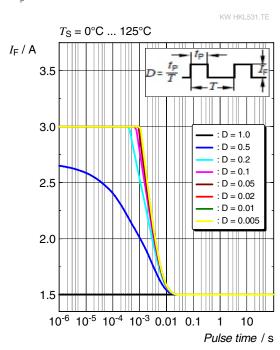
## Max. Permissible Forward Current

$$I_{\rm F}$$
 = f (T); 0.7 \*  $\Phi_{\rm V\,min.}$  of bin F0;  $R_{\rm th\,real\,max.}$ 



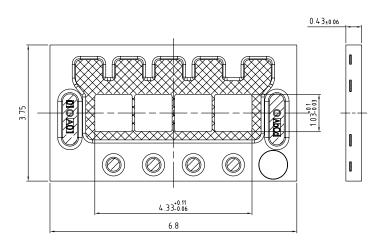
## Permissible Pulse Handling Capability

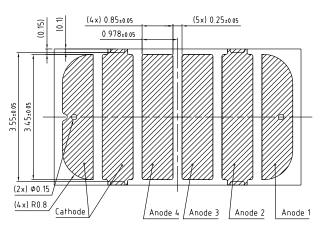
 $I_F = f(t_p)$ ; D: Duty cycle





### **Dimensional Drawing** 8)





general tolerance ±0.1 Lead finish Au

C67062-A0182-A1-04

### **Further Information:**

**Approximate Weight:** 42.0 mg

Corrosion test: Class: 3B

Test condition: 40°C / 90 % RH / 15 ppm H<sub>2</sub>S / 14 days (stricter than IEC

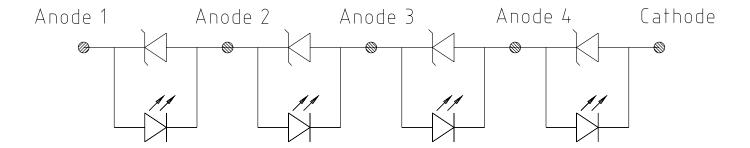
60068-2-43)

**ESD advice:** The device is protected by ESD device which is connected in parallel to the

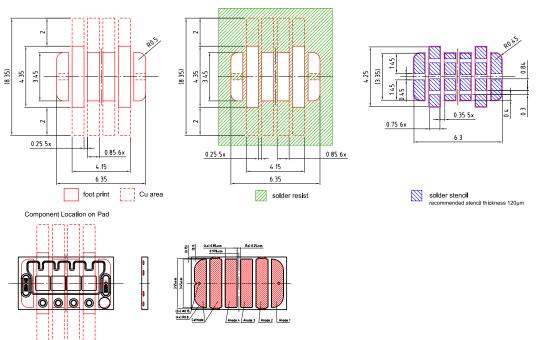
Chip.



#### **Electrical Internal Circuit**



#### Recommended Solder Pad 8)



E062.3010.215 -02

For superior solder joint connectivity results we recommend soldering under standard nitrogen atmosphere. Package not suitable for ultra sonic cleaning. To ensure a high solder joint reliability and to minimize the risk of solder joint cracks, the customer is responsible to evaluate the combination of PCB board and solder paste material for his application.



### **Reflow Soldering Profile**

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E



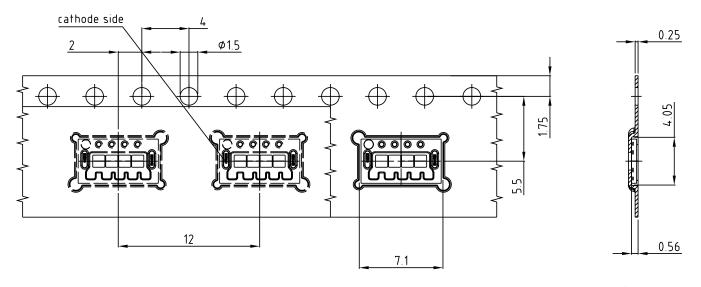
Profile Feature	Symbol	Pb-Free (SnAgCu) Assembly			Unit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat*)			2	3	K/s
25 °C to 150 °C					
Time t <sub>s</sub>	$t_s$	60	100	120	S
$T_{Smin}$ to $T_{Smax}$					
Ramp-up rate to peak*)			2	3	K/s
$T_{Smax}$ to $T_{P}$					
Liquidus temperature	$T_L$		217		°C
Time above liquidus temperature	$t_{\scriptscriptstyle \perp}$		80	100	S
Peak temperature	$T_{P}$		245	260	°C
Time within 5 °C of the specified peak	t <sub>P</sub>	10	20	30	S
temperature T <sub>P</sub> - 5 K					
Ramp-down rate*			3	6	K/s
T <sub>P</sub> to 100 °C					
Time				480	S
25 °C to T <sub>P</sub>					

All temperatures refer to the center of the package, measured on the top of the component



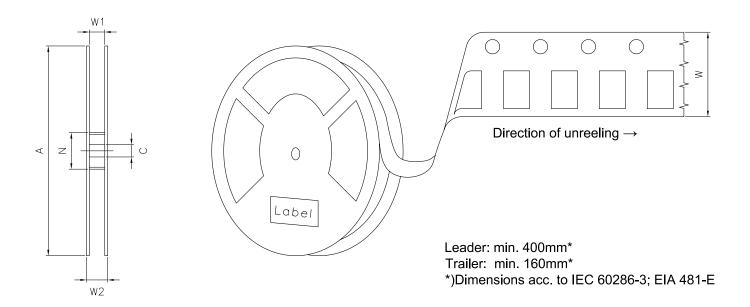
<sup>\*</sup> slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range

# Taping 8)





## Tape and Reel 9)



### **Reel Dimensions**

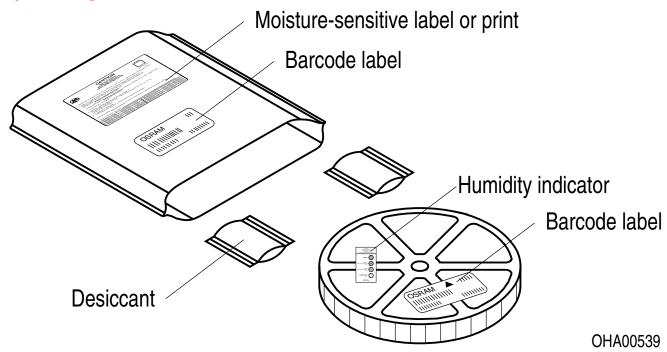
Α	W	$N_{\min}$	$W_1$	$W_{2\text{max}}$	Pieces per PU
180 mm	12 + 0.3 / - 0.1 mm	60 mm	12.4 + 2 mm	18.4 mm	1500



### **Barcode-Product-Label (BPL)**



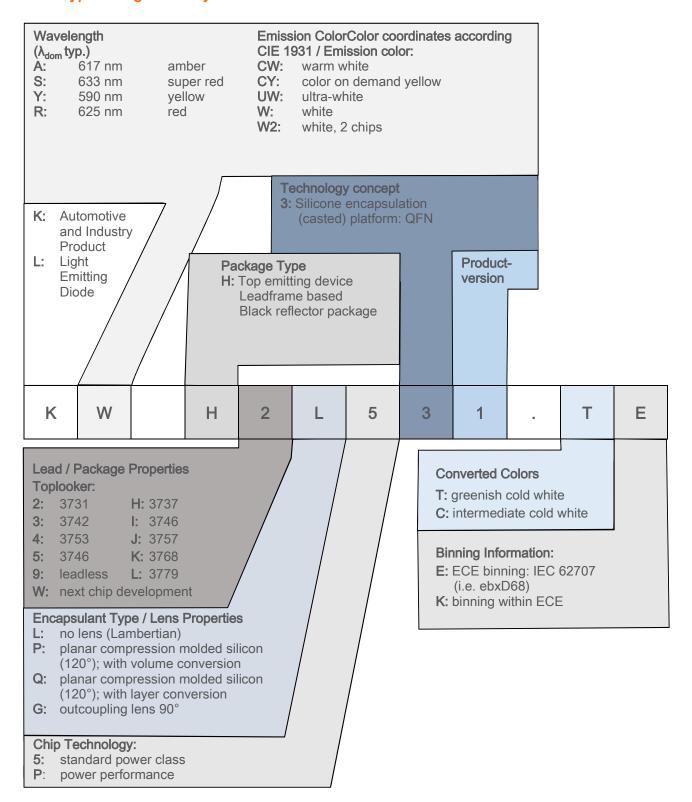
### Dry Packing Process and Materials 8)



Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.



#### **Type Designation System**





#### **Notes**

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet falls into the class moderate risk (exposure time 0.25 s). Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit www.osram-os.com/appnotes



#### **Disclaimer**

#### Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on the OSRAM OS website.

#### **Packing**

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

#### Product and functional safety devices/applications or medical devices/applications

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

OSRAM OS products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using OSRAM OS components in product safety devices/applications or medical devices/applications, buyer and/or customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and buyer and /or customer will analyze and coordinate the customer-specific request between OSRAM OS and buyer and/or customer.



### Glossary

- Brightness: Brightness values are measured during a current pulse of typically 25 ms, with an internal reproducibility of ±8 % and an expanded uncertainty of ±11 % (acc. to GUM with a coverage factor of k = 3).
- Reverse Operation: This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LED.
- Chromaticity coordinate groups: Chromaticity coordinates are measured during a current pulse of typically 25 ms, with an internal reproducibility of  $\pm 0.005$  and an expanded uncertainty of  $\pm 0.01$  (acc. to GUM with a coverage factor of k = 3).
- Forward Voltage: The forward voltage is measured during a current pulse of typically 8 ms, with an internal reproducibility of ±0.05 V and an expanded uncertainty of ±0.1 V (acc. to GUM with a coverage factor of k = 3).
- 5) **Thermal Resistance:** Rth max is based on statistic values (6σ).
- Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- Characteristic curve: In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- 9) Tape and Reel: All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.



### KW HKL531.TE

Revisio	Revision History				
Version	Date	Change			
1.3	2019-02-12	Ordering Information Brightness Groups Derating (Diagrams) Type Designation System Notes Disclaimer			
1.4	2019-08-22	Ordering Information Characteristics Brightness Groups Group Name on Label Derating (Diagrams) Recommended Solder Pad Notes Disclaimer			
1.5	2020-01-30	Features Schematic Transportation Box Dimensions of Transportation Box			
1.6	2020-10-13	Further Information Recommended Solder Pad Glossary			



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